

April 2016

FDC642P_F085

P-Channel PowerTrench® MOSFET -20V, -4A, 100m Ω

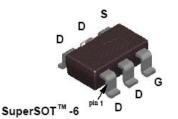
Features

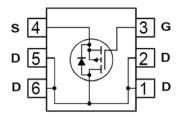
- Typ $R_{DS(on)}$ = 52.5m Ω at V_{GS} = -4.5V, I_D = -4A
- Typ $R_{DS(on)}$ = 75.3m Ω at V_{GS} = -2.5V, I_D = -3.2A
- Fast switching speed
- Low gate charge(6.9nC typical)
- High performance trench technology for extremely low R_{DS(on)}
- SuperSOTTM-6 package:small footprint(72% smaller than standard SO-8);low profile(1mm thick).
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Load switch
- Battery protection
- Power management







MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain to Source Voltage	-20	V	
V_{GS}	Gate to Source Voltage		±8	V
	Drain Current Continuous (V _{GS} = 4.5V)	-4	۸	
I _D	Pulsed		-20	Α
E _{AS}	Single Pulse Avalanche Energy (N	Note 1)	72	mJ
P_D	Power Dissipation		1.2	W
T _J , T _{STG}	Operating and Storage Temperature		-55 to +150	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	30	°C/W	
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, 1in ² copper pad area		103	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDC642P	FDC642P_F085	SSOT-6	7"	8mm	3000 units

- 1: Starting T_J = 25°C, L = 14.1mH, I_{AS} = -3.2A 2: A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as Fairchild has officially announced in Aug 2014.

Units

Max

Тур

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Parameter

Off Characteristics							
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_G$	_S = 0V	-20	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16V$,		-	-	-1	цΑ
		$V_{GS} = 0V$	$T_A = 150^{\circ}C$	-	-	-250	μΑ
loss	Gate to Source Leakage Current	$V_{CC} = +8V$	·	-	_	±100	nA

Test Conditions

Min

On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.4	-0.7	-1.5	V
r	rps(cs) Drain to Source On Resistance	$I_D = -4A, V_{GS} = -4.5V$	-	52.5	65	
		$I_D = -3.2A, V_{GS} = -2.5V$	-	75.3	100	mΩ
'DS(on)		$I_D = -4A$, $V_{GS} = -4.5V$ $T_J = 125^{\circ}C$	-	72.7	105	11122
g _{FS}	Forward Transconductance	$I_D = -4A$, $V_{DD} = -5V$	-	10	-	S

Dynamic Characteristics

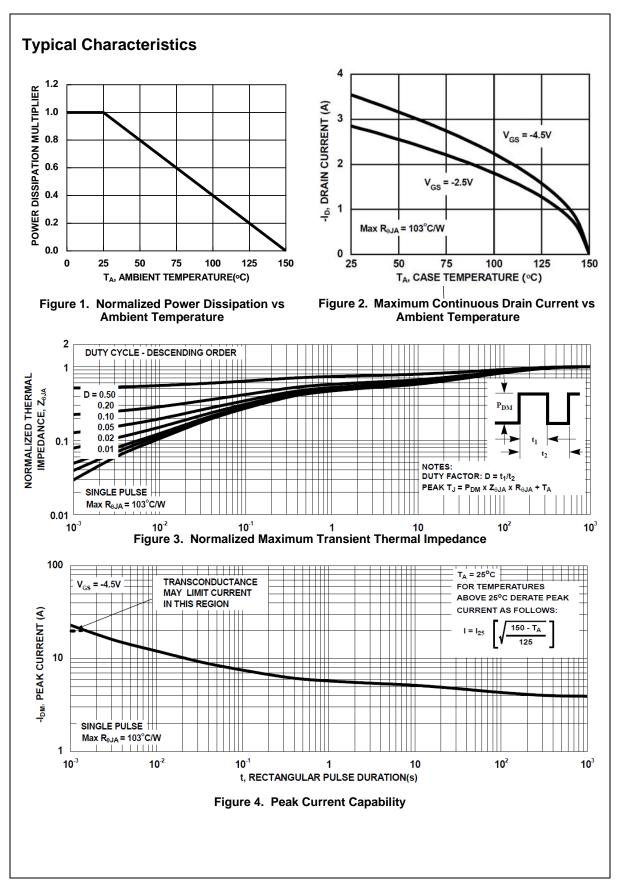
C _{iss}	Input Capacitance	101/11/		i	630	ı	pF
C _{oss}	Output Capacitance	── v _{DS} = -10v, v _{GS} = — f = 1MHz	$V_{DS} = -10V, V_{GS} = 0V,$		160	-	pF
C _{rss}	Reverse Transfer Capacitance	-1 = 11VII 12		-	65	-	pF
R_G	Gate Resistance	f = 1MHz	f = 1MHz		4.4	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at -4.5V	$V_{GS} = 0 \text{ to } -4.5 \text{V}$	V _{GS} = 0 to -4.5V		6.9	9.0	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DD} = -10V$ $I_{D} = -4A$		-	1.2	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		1 _D = -4A		1.8	-	nC

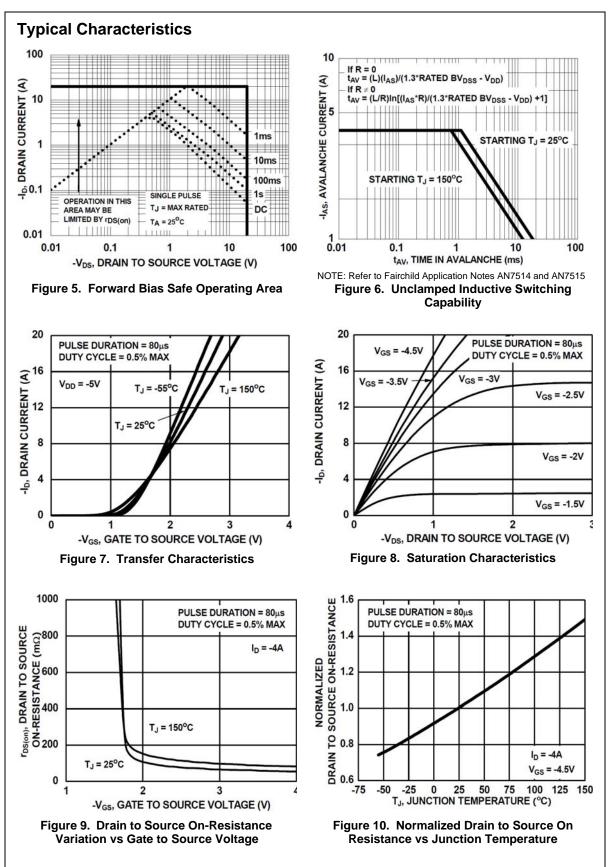
Switching Characteristics

t _{on}	Turn-On Time		-	-	23	ns
t _{d(on)}	Turn-On Delay Time	Ī [-	7.3	-	ns
t _r	Rise Time	$V_{DD} = -10V, I_{D} = -1A$ $V_{GS} = -4.5V, R_{GS} = 6\Omega$	-	5.5	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -4.5 \text{ V}, R_{GS} = 602$		23.2	-	ns
t _f	Fall Time		-	9.6	-	ns
t _{off}	Turn-Off Time		-	-	53	ns

Drain-Source Diode Characteristics

V	V_{SD} Source to Drain Diode Voltage $ \frac{I_{SD} = -1.3A}{I_{SD} = -0.65A} $	I _{SD} = -1.3A	-	-	-1.25	\/
v SD		$I_{SD} = -0.65A$	ı	•	-1.0	v
t _{rr}	Reverse Recovery Time	_ 1 3 \ d /dt _ 100 \/	-	17	22	ns
Q _{rr}	Reverse Recovery Charge	$I_{SD} = -1.3A$, $dI_{SD}/dt = 100A/\mu s$	ı	5.6	7.3	nC





Typical Characteristics

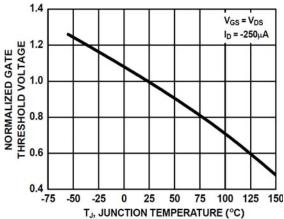


Figure 11. Normalized Gate Threshold Voltage vs
Junction Temperature

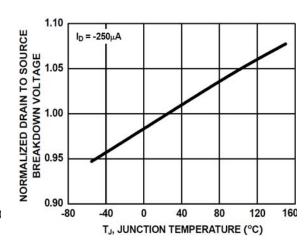


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

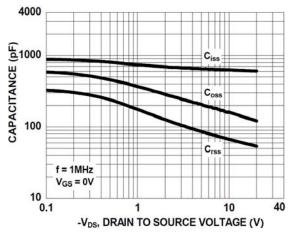


Figure 13. Capacitance vs Drain to Source Voltage

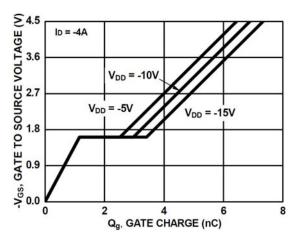
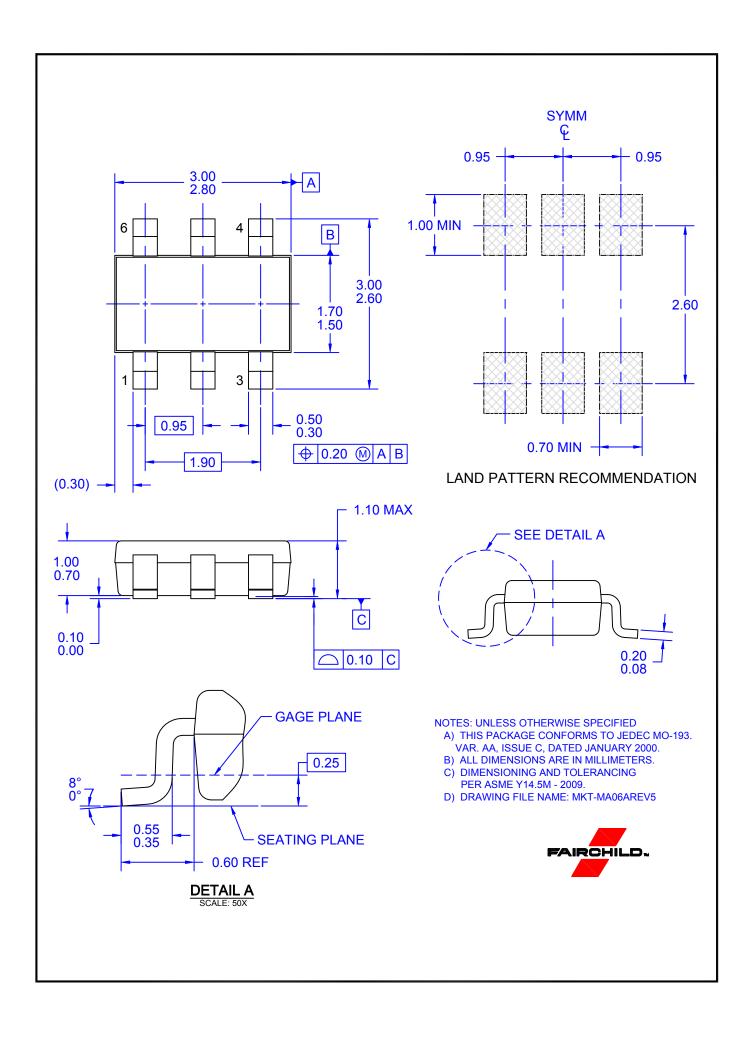


Figure 14. Gate Charge vs Gate to Source Voltage







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Definition of Terms							
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